Enhancement of Mechanical Response in MoS₂ Drum Resonator using Parametric Amplification

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Abstract

We report enhancement of mechanical response in MoS2 drum resonator using parametric amplification and achieve ~ 10 dB gain [1]. NEMS resonators based on 2D materials have very poor quality factor ~ 100 at room temperature and worse at higher temperature. We show quality factor enhancement in the resonator parametric amplification at 397 K (Figure 2). The signal enhancement is similar to the recently reported NEMS devices However, the amplification is significantly lower as compared to the reported MEMS devices [4]. We investigate the effect of Duffing (cubic) non-linearity in the current work and show that it plays significant role in the maximum achievable gain from devices **NEMS** using parametric amplification. The experiments performed usina direct capacitive measurement technique on near insulating \sim 1G Ω device. This shows the ability to perform electrical capacitive actuation and detection technique in very high resistance NEMS devices.

References

- [1] Ruger D. et al, Phys. Rev. Lett.(1991) 699-702
- [2] Mathew John P. et al, Nat. Nano. (2016) 747-751
- [3] Karabalin R. B. et al, App. Phys. Lett. (2010) 97

Figures

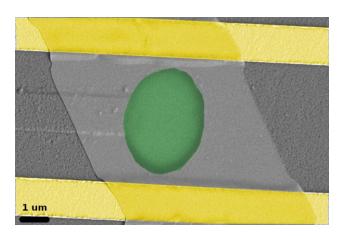


Figure 1: False Coloured Scanning Electron Micrograph of the MoS₂ drum resonator

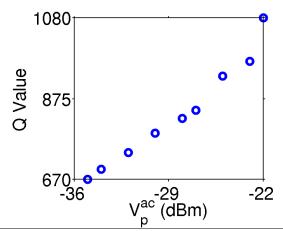


Figure 2: Enhancement of quality factor with applied pump force